RUMENTS Data sheet acquired from Harris Semiconductor SCHS099B - Revised January 2003

CD40109B Types

CMOS Quad Low-to-High Voltage Level Shifter Features:

High-Voltage Types (20-Volt Rating)

CD40109B contains four low-tohigh-voltage level-shifting circuits. Each circuit will shift a low-voltage digital-logic input signal (A, B, C, D) with logical 1 = VCC and logical 0 = VSS to a higher-voltage output signal (E, F, G, H) with logical 1 = VDD and logical 0 = VSS.

The CD40109, unlike other low-to-high level-shifting circuits, does not require the presence of the high-voltage supply (V_{DD}) before the application of either the low-voltage supply (V_{CC}) or the input signals. There are no restrictions on the sequence of application of V_{DD}, V_{CC}, or the input signals. In addition, with one exception there are no restrictions on the relative magnitudes of the supply voltages or input signals within the device maximum ratings, provided that the input signal swings between V_{SS} and at least 0.7 V_{CC}; V_{CC} may exceed V_{DD} , and input signals may exceed V_{CC} and V_{DD} . When operated in the mode $V_{CC} > V_{DD}$, the CD40109 will operate as a high-to-low level-shifter.

The CD40109 also features individual threestate output capability. A low level on any of the separately enabled three-state output controls produces a high-impedance-state in the corresponding output.

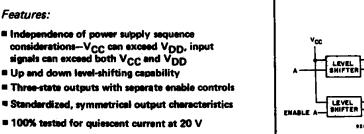
The CD40109B-Series types are supplied in 16-lead ceramic dual-in-line packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (NSR suffix), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

Applications:

- High-or-low level-shifting with three-state outputs for unidirectional or bidirectional hussing
- Isolation of logic subsystems using separate power supplies from supply sequencing, supply loss and supply regulation **considerations**

	TRUTH TABLE					
INF	INPUTS					
Ă, B, C, D	ENABLE A, B, C, D	E, F, G, H				
0	1	0				
1	1	1 1				
X	0	Z				

Z = HIGH IMPEDANCE LOGIC 0 = LOW(V88) X = DON'T CARE LOGIC 1 = VCC at INPUTS and VDD at OUTPUTS



FUNCTIONAL DIAGRAM

(1 of 4 units)

Maximum input current of 1 µA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C

Noise margin (full package-temperature range)

Up and down level-shifting capability

- = 1 V at V_{CC} = 5 V, V_{DD} = 10 V
- = 2 V at V_{CC} = 10 V, V_{DD} = 15 V
- 5-V, 10-V, and 15-V perametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices'

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIN	UNITS		
CHARACTERISTIC	MIN.	MAX.		
Supply-Voltage Range (For TA =				
Full Package-Temperature Range)	3	18	V.	

MAXIMUM RATINGS, Absolute-Maximum Values: D

DC SUPPLY-VOLTAGE RANGE, (V _{DD})	
Voltages referenced to VSS Terminal)0.5V to +20V	
OUTPUT VOLTAGE RANGE, ALL OUTPUTS	
DC INPUT CURRENT, ANY ONE INPUT	
POWER DISSIPATION PER PACKAGE (PD):	
For T _A = -55°C to +100°C	
For $T_A = +100^{\circ}C$ to $+125^{\circ}C$ Derate Linearity at $12mW/^{\circ}C$ to $200mW$	
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR T _A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW	
OPERATING-TEMPERATURE RANGE (T _A)55°C to +125°C	
STORAGE TEMPERATURE RANGE (Tstg)65°C to +150°C	
LEAD TEMPERATURE (DURING SOLDEBING):	

At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max +265°C

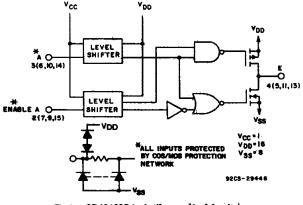


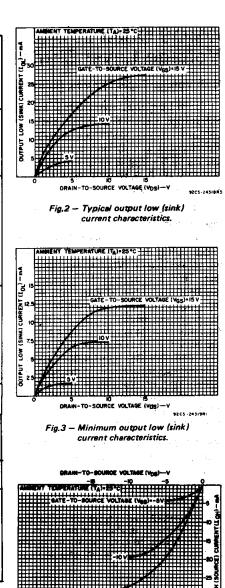
Fig.1 - CD40109B logic diagram (1 of 4 units).

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Independence of power supply sequence

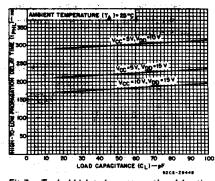
STATIC ELECTRICAL CHARACTERISTICS

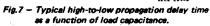
CHARACTER-	COND			LIN	IITS AT	INDICA	TED TE	MPERA	UNITS		
ISTIC	Vo (V)	VIN (V)	VDD (V)	-55	40	+85	+125	Min.	+25 Typ.	Max.	
Quiescent Device		0,5	5	1	1	30	30		0.02	1	
Current,	-	0,10	10	2	2	60	60	-	0.02	2	
IDD Max.	-	0,15	15	4	- 4	120	120	-	0.02	4	μΑ
	-	0,20	20	20	20	600	600		0.04	20	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1.	-	
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	- 4	ar.
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	34	6.8	<u> </u>	1
Output High	4.6	.0,5	.5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mΑ
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	., - -3.2	_ ·	1
Current,	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-]
IOH Min.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	. – .	1
Output Voltage:	-	0,5	5		0	.05		-	0	0.05	· · · · ·
Low-Level,	_	0,10	10		0	.05		-	0	0.05	1
VOL Max.	_	0,15	15		0	.05	<u> </u>	-	0	0.05	
Output Voltage:	_	0,5	5		4	.95		4.95	. 5	-	1.
High-Level,		0,10	10		9	.95		9.95	10	– .]
VOH Min.	·· _ ··	0,15	15		14	:95		14.95	15	- '	
Input Current IN Max.		0,18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μA
3-State Output Leakage Current IOUT Max.		0,18	18	±0.4	±0.4	±12	±12	- 11 FA 	±10-4	±0.4	μΑ
	Vo (V)	V _{CC} (V)	V _{DD} (V)			2 C		n po se			
Input Low Voltage,	1,9	- 5	10		1	.5			-	1.5	
VIL Max.	1.5, 13.5	10	15			3		. —	-	3	
Input High	1,9	5	10		:	3.5	•	3.5	-	-	
Voltage, VIH Min.	1.5,13.5	10	15			7	· .	7	ar <u>an</u> Tagairtí		





OUTPUT





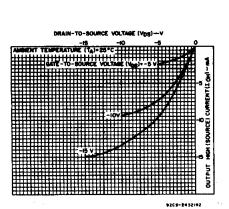


Fig.5 - Minimum output high (source)current characteristics.

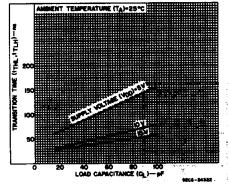


Fig.6 - Typical transition time as a function of load capacitance.

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C, Input t_r, t_f = 20 ns, C_L = 50 pF, R_L = 200 k Ω unless otherwise specified

CHARACTERISTIC	SHIFTING	Vcc	VDD					
	MODE	(V)	(V)	Typ.	Max.			
ropagation Delay – Data Input		5	10	300	600			
to Output:	L-H	5	15	220	440	ł		
High-to-Low Level, tpHL		10	15	180	360			
High to Low Level, IPHL		10	5	250	500	ns		
	H–L	15	5	250	500			
		15	10	120	240			
		5	10	130	260			
	L-H	5	15	120	240	. e		
Low-to-High Level, tpLH		10	15	70	140	ns		
		10	5	230	460			
	H-L	15	5	230	- 460			
State Disable Delav:		15	10	80	160			
-State Disable Delay:		5	10	60	120			
$R_{L} = 1 k\Omega$	L-H	5	15	75	150			
Output High to High		10	15	35	70	ns		
Impedance, tPHZ		10	5	200	400	113		
	H-L	15	5	200	400			
· · · · · · · · · · · · · · · · · · ·		15	10	40	80	ļ		
		5	10	370	740			
Output Low to High	L-H	5	15	300	600			
Impedance, tpLZ		10	15	250	500	ns		
		10	5	250	500	['''		
	H-L	15	5	250	500			
		15	10	130	260			
9 1		5	10	320	640	ns		
High Impedance to	L-H	5	15	230	460			
Output High, tpZH		10	15	180	360			
Cuthat High, th2H		10	5	300	600			
	H-L	15	5	300	600			
		15	10	130	260			
		5	10	100	200			
High Impedance to	L-H	5	15	80	160			
Output Low, tPZL		10	15	40	80	ns		
		10 15	5 5	200	400 400	1		
	H-L	15	10	200 40	400 80			
		t. 125 -				 		
	1-H	• 5 • 5	્ર્ય10 \$15	50 40	100 80			
		10	15	40	80			
ransition Time, TTHL, TTLH		10.1	the second s			ns		
	1995年1月末日 1997年1月1日	10 + · ·	5	100 100	200 200			
	H–L	15	10	50	100			
nput Capacitance, Ci		Any		5	7.5			
						pF		

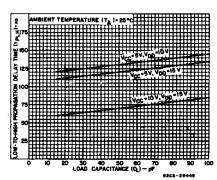
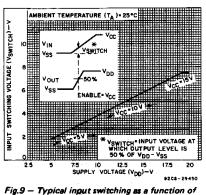


Fig.8 - Typical low-to-high propagation delay time as a function of load capacitance.



3

COMMERCIAL CMOS HIGH VOLTAGE ICS

Fig.9 - Typical input switching as a function of high-level supply voltage.

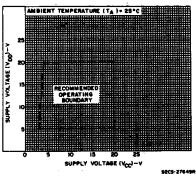


Fig. 10 - High-level supply voltage vs. Iow-level supply voltage.

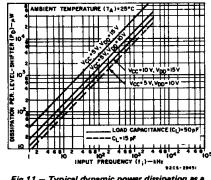


Fig.11 - Typical dynamic power dissipation as a function of input frequency.

CD40109B Types

TEST CIRCUITS

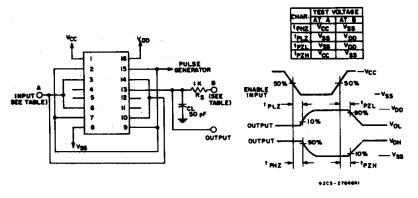
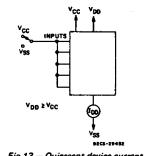
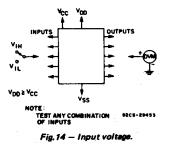
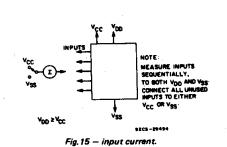


Fig. 12 - Output enable delay times test circuit and waveforms.









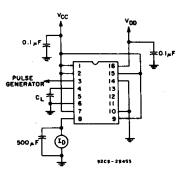
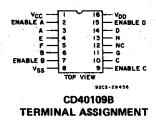
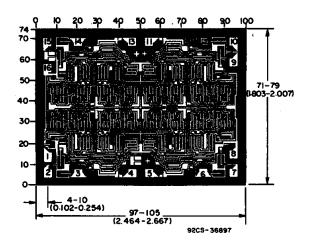


Fig. 16 - Dynamic power dissipation test circuit.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).



Dimensions and pad layout for CD40109BH.



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CD40109BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD40109BE	Samples
CD40109BF	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD40109BF	Samples
CD40109BF3A	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD40109BF3A	Samples
CD40109BNSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD40109B	Samples
CD40109BNSRE4	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD40109B	Samples
CD40109BPW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM0109B	Samples
CD40109BPWE4	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM0109B	Samples
CD40109BPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM0109B	Samples
CD40109BPWRE4	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM0109B	Samples
CD40109BPWRG4	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM0109B	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



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PACKAGE OPTION ADDENDUM

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD40109B, CD40109B-MIL :

- Catalog : CD40109B
- Automotive : CD40109B-Q1, CD40109B-Q1
- Military : CD40109B-MIL

NOTE: Qualified Version Definitions:

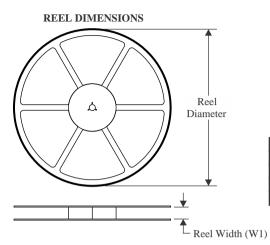
- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications

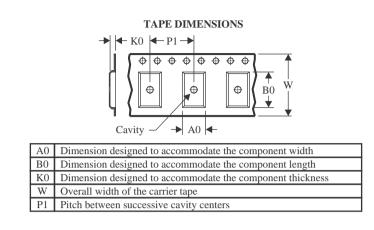


Texas

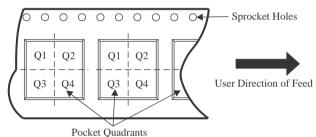
STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



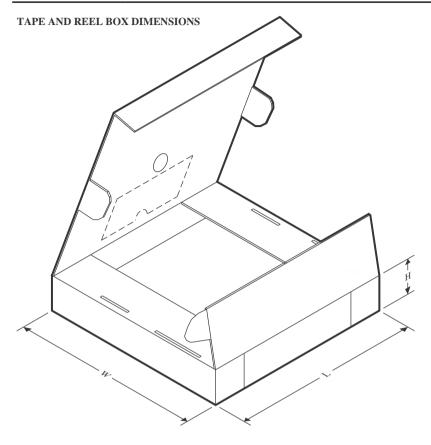
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD40109BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD40109BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

3-Jun-2022



*All dimensions are nominal

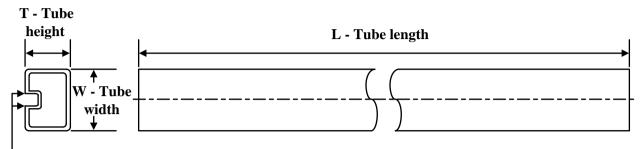
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD40109BNSR	SO	NS	16	2000	367.0	367.0	38.0
CD40109BPWR	TSSOP	PW	16	2000	356.0	356.0	35.0

TEXAS INSTRUMENTS

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3-Jun-2022

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD40109BE	N	PDIP	16	25	506	13.97	11230	4.32
CD40109BE	N	PDIP	16	25	506	13.97	11230	4.32
CD40109BPW	PW	TSSOP	16	90	530	10.2	3600	3.5
CD40109BPWE4	PW	TSSOP	16	90	530	10.2	3600	3.5

NS0016A



PACKAGE OUTLINE

SOP - 2.00 mm max height

SOP



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- Per ASME Y14.5M.
 This drawing is subject to change without notice.
 This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



NS0016A

EXAMPLE BOARD LAYOUT

SOP - 2.00 mm max height

SOP



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



NS0016A

EXAMPLE STENCIL DESIGN

SOP - 2.00 mm max height

SOP



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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